








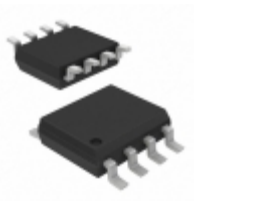
	<b>ZXM66P02N8TA</b>	
	<b>Hersteller-Teilenummer:</b>	ZXM66P02N8TA
	<b>Hersteller / Marke:</b>	Diodes Incorporated
	<b>Teil der Beschreibung:</b>	MOSFET P-CH 20V 8A 8-SOIC
	<b>Datenblätter:</b>	 <a href="#">ZXM66P02N8TA.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 120230 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	ZXM66P02N8TA
Hersteller	Diodes Incorporated
Beschreibung	MOSFET P-CH 20V 8A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	120230 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	1.56W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6.4A (Ta)
Rds On (Max) @ Id, Vgs	25 mOhm @ 3.2A, 4.5V
VGS (th) (Max) @ Id	700mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	43.3nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2068pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V
Vgs (Max)	±12V
Verpackung	Tape & Reel (TR)



ZXM66P02N8TA ist neu im Original, Suche ZXM66P02N8TA Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie ZXM66P02N8TA Diodes Incorporated mit Garantie und Vertrauen. Anfrage ZXM66P02N8TA: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>ZXM66P02N8</b> Zetex ZXM66P02N8 Zetex</p>	 <p><b>ZXM66P03N8TC</b> Z ZXM66P03N8TC Z</p>	 <p><b>ZXM64P03XTC</b> Diodes Incorporated MOSFET P-CH 30V 3.8A 8MSOP</p>	 <p><b>ZXM66N03N8TA</b> Diodes Incorporated MOSFET N-CH 30V 9A 8-SOIC</p>
 <p><b>ZXM66P03N8TA</b> Diodes Incorporated MOSFET P-CH 30V 7.9A 8-SOIC</p>	 <p><b>ZXM66P03N8-7-F</b> DIODES ZXM66P03N8-7-F DIODES</p>	 <p><b>ZXM66P02N8T</b> ZETEX ZXM66P02N8T ZETEX</p>	 <p><b>ZXM66P02N8TC</b> Diodes Incorporated MOSFET P-CH 20V 6.4A 8SOIC</p>

### heiße Teile

Mehr

 ZXM62P03E6TA	 ZXM62P03GTA	 ZXM63C02	 ZXM63C03	 ZXM63N03
 ZXM64N02	 ZXM64N02XTA	 ZXM64N02XTC	 ZXM64N035	 ZXM64N035GTA
 ZXM64N035L3	 ZXM64N03XTA	 ZXM64P02	 ZXM64P02X	 ZXM64P02XTA
 ZXM64P02XTC	 ZXM64P035	 ZXM64P035G	 ZXM64P035GTA	 ZXM64P035L3
 ZXM64P03XTA	 ZXM64P03XTC	 ZXM66N03N8TA	 ZXM66P02N8	 ZXM66P02N8T
 ZXM66P02N8TC	 ZXM66P03N8	 ZXM66P03N8-7-F	 ZXM66P03N8TA	 ZXM66P03N8TC
 ZXMC10A816N8	 ZXMC10A816N8TC	 ZXMC3A16	 ZXMC3A16DN8	 ZXMC3A16DN8TA
 ZXMC3A16DN8TC	 ZXMC3A17DN8	 ZXMC3A17DN8TA	 ZXMC3A17DN8TC	 ZXMC3A18DN8
 ZXMC3A18DN8TA	 ZXMC3A18DN8TC	 ZXMC3AM832TA	 ZXMC3AMCTA	 ZXMC3F31DN8
 ZXMC3F31DN8TA	 ZXMC3F31DN8TC	 ZXMC4559	 ZXMC4559DN8	 ZXMC4559DN8TA

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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